

# Bias Resistor Transistors

## PNP Silicon Surface Mount Transistors With Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-723 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SOT-723 Package can be Soldered using Wave or Reflow.
- Available in 4 mm, 8000 Unit Tape & Reel
- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

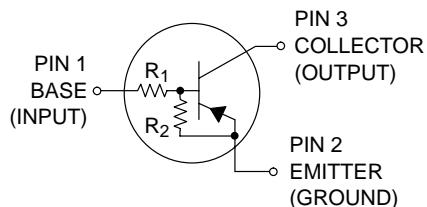
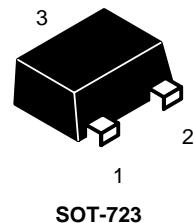
Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc

### THERMAL CHARACTERISTICS

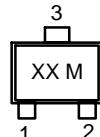
Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	260 (Note 1) 600 (Note 2) 2.0 (Note 1) 4.8 (Note 2)	mW mW/ $^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	480 (Note 1) 205 (Note 2)	$^\circ\text{C/W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 x 1.0 inch Pad

### LDTA114EM3T5G Series S-LDTA114EM3T5GSeries



### MARKING DIAGRAM



xx = Specific Device Code  
M = Date Code



LESHAN RADIO COMPANY, LTD.

**LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series**

**ORDERING INFORMATION, DEVICE MARKING AND RESISTOR VALUES**

Device	Marking	R1 (K)	R2 (K)	Package	Shipping
LDTA114EM3T5G	S-LDTA114EM3T5G	6A	10		
LDTA124EM3T5G	S-LDTA124EM3T5G	6B	22		
LDTA144EM3T5G	S-LDTA144EM3T5G	6C	47		
LDTA114YM3T5G	S-LDTA114YM3T5G	6D	10		
LDTA114TM3T5G	S-LDTA114TM3T5G	6E	10		
LDTA143TM3T5G	S-LDTA143TM3T5G	6F	4.7		
LDTA123EM3T5G	S-LDTA123EM3T5G	6H	2.2	2.2	SOT-723
LDTA143EM3T5G	S-LDTA143EM3T5G	6J	4.7		
LDTA143ZM3T5G	S-LDTA143ZM3T5G	6K	4.7		
LDTA124XM3T5G	S-LDTA124XM3T5G	6L	22		
LDTA123JM3T5G	S-LDTA123JM3T5G	6M	2.2		
LDTA115EM3T5G	S-LDTA115EM3T5G	6N	100		
LDTA144WM3T5G	S-LDTA144WM3T5G	6P	47		
			22		8000/Tape & Reel

**LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector–Base Cutoff Current ( $V_{CB} = 50 \text{ V}$ , $I_E = 0$ )	$I_{CBO}$	–	–	100	nAdc
Collector–Emitter Cutoff Current ( $V_{CE} = 50 \text{ V}$ , $I_B = 0$ )	$I_{CEO}$	–	–	500	nAdc
Emitter–Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}$ , $I_C = 0$ )	$I_{EBO}$	–	–	0.5	mAdc
LDTA114EM3T5G		–	–	0.2	
LDTA124EM3T5G		–	–	0.1	
LDTA144EM3T5G		–	–	0.2	
LDTA114YM3T5G		–	–	0.9	
LDTA114TM3T5G		–	–	1.9	
LDTA143TM3T5G		–	–	2.3	
LDTA123EM3T5G		–	–	1.5	
LDTA143EM3T5G		–	–	0.18	
LDTA143ZM3T5G		–	–	0.13	
LDTA124XM3T5G		–	–	0.2	
LDTA123JM3T5G		–	–	0.05	
LDTA115EM3T5G		–	–	0.13	
LDTA144WM3T5G		–	–		
Collector–Base Breakdown Voltage ( $I_C = 10 \mu\text{A}$ , $I_E = 0$ )	$V_{(BR)CBO}$	50	–	–	Vdc
Collector–Emitter Breakdown Voltage (Note 3.) ( $I_C = 2.0 \text{ mA}$ , $I_B = 0$ )	$V_{(BR)CEO}$	50	–	–	Vdc

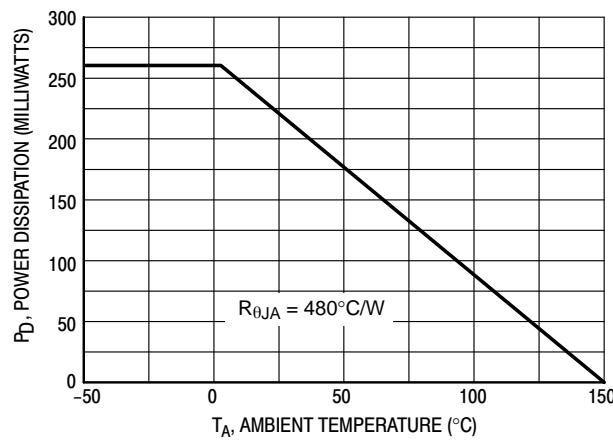
**ON CHARACTERISTICS** (Note 3.)

DC Current Gain ( $V_{CE} = 10 \text{ V}$ , $I_C = 5.0 \text{ mA}$ )	LDTA114EM3T5G LDTA124EM3T5G LDTA144EM3T5G LDTA114YM3T5G LDTA114TM3T5G LDTA143TM3T5G LDTA123EM3T5G LDTA143EM3T5G LDTA143ZM3T5G LDTA124XM3T5G LDTA123JM3T5G LDTA115EM3T5G LDTA144WM3T5G	$h_{FE}$	35 60 80 80 160 160 8.0 15 80 80 80 80 80	60 100 140 140 250 250 15 27 140 130 140 150 140	– – – – – – – – – – – – – –		
Collector–Emitter Saturation Voltage ( $I_C = 10 \text{ mA}$ , $I_E = 0.3 \text{ mA}$ ) ( $I_C = 10 \text{ mA}$ , $I_B = 5 \text{ mA}$ ) LDTA123EM3T5G ( $I_C = 10 \text{ mA}$ , $I_B = 1 \text{ mA}$ ) LDTA114TM3T5G/LDTA143TM3T5G/ LDTA143ZM3T5G/LDTA124XM3T5G/LDTA143EM3T5G	$V_{CE(\text{sat})}$	–	–	0.25	Vdc		
Output Voltage (on) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 2.5 \text{ V}$ , $R_L = 1.0 \text{k}\Omega$ )	LDTA114EM3T5G LDTA124EM3T5G LDTA114YM3T5G LDTA114TM3T5G LDTA143TM3T5G LDTA123EM3T5G LDTA143EM3T5G LDTA143ZM3T5G LDTA124XM3T5G LDTA123JM3T5G ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 3.5 \text{ V}$ , $R_L = 1.0 \text{k}\Omega$ ) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 5.5 \text{ V}$ , $R_L = 1.0 \text{k}\Omega$ ) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 4.0 \text{ V}$ , $R_L = 1.0 \text{k}\Omega$ )	$V_{OL}$	– – – – – – – – – – – – – – – – – – – –	– –	0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	Vdc	
Output Voltage (off) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 0.5 \text{ V}$ , $R_L = 1.0 \text{k}\Omega$ ) ( $V_{CC} = 5.0 \text{ V}$ , $V_B = 0.25 \text{ V}$ , $R_L = 1.0 \text{k}\Omega$ )	LDTA114TM3T5G LDTA143TM3T5G LDTA123EM3T5G LDTA143EM3T5G	$V_{OH}$	4.9	–	–	Vdc	

3. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%

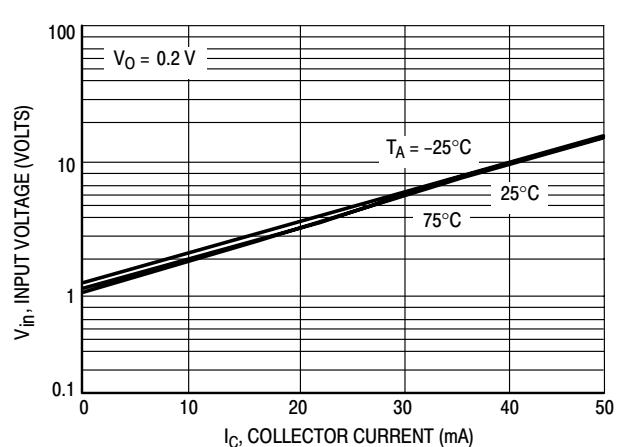
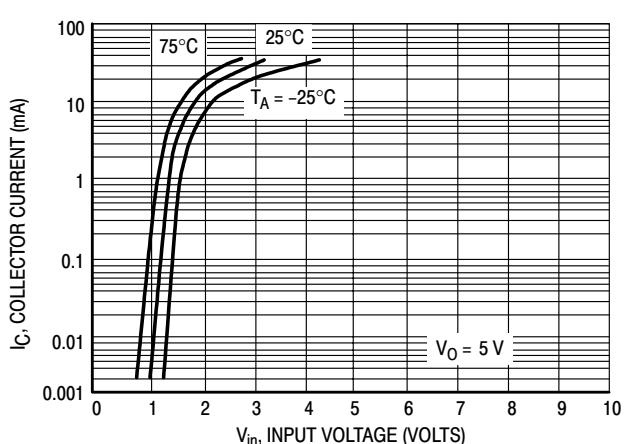
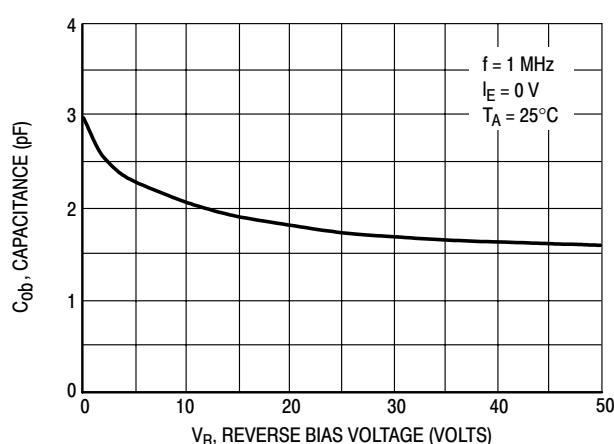
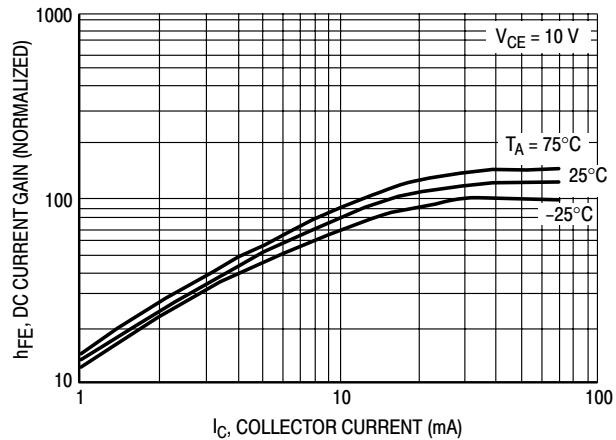
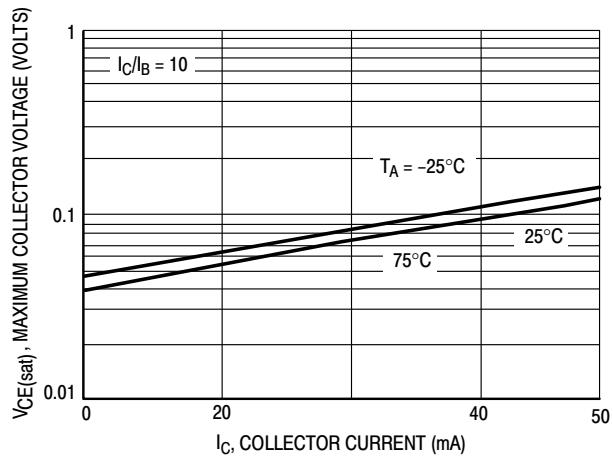
**LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
Input Resistor	R1	7.0	10	13	kΩ
		15.4	22	28.6	
		32.9	47	61.1	
		7.0	10	13	
		7.0	10	13	
		3.3	4.7	6.1	
		1.5	2.2	2.9	
		3.3	4.7	6.1	
		3.3	4.7	6.1	
		15.4	22	28.6	
		1.54	2.2	2.86	
		70	100	130	
		32.9	47	61.1	
Resistor Ratio /	$R_1/R_2$	0.8	1.0	1.2	
		0.17	0.21	0.25	
		—	—	—	
		0.8	1.0	1.2	
		0.055	0.1	0.185	
		0.38	0.47	0.56	
		0.038	0.047	0.056	
		1.7	2.1	2.6	


**Figure 1. Derating Curve**

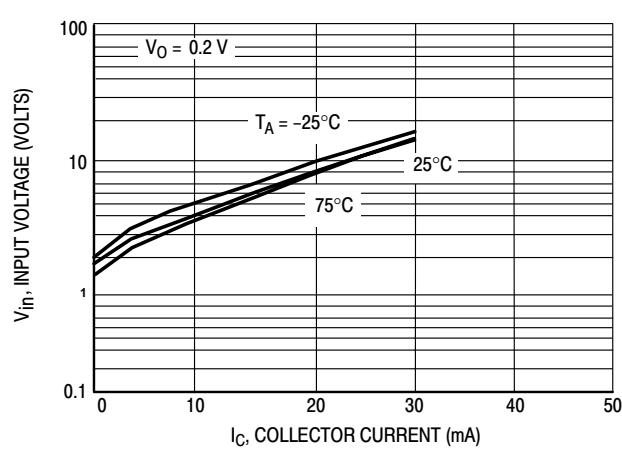
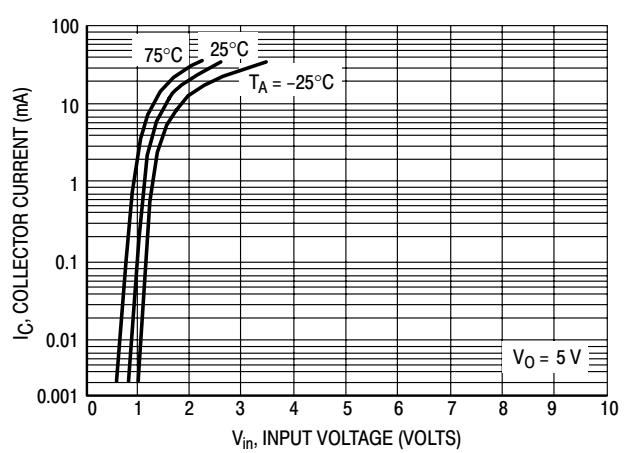
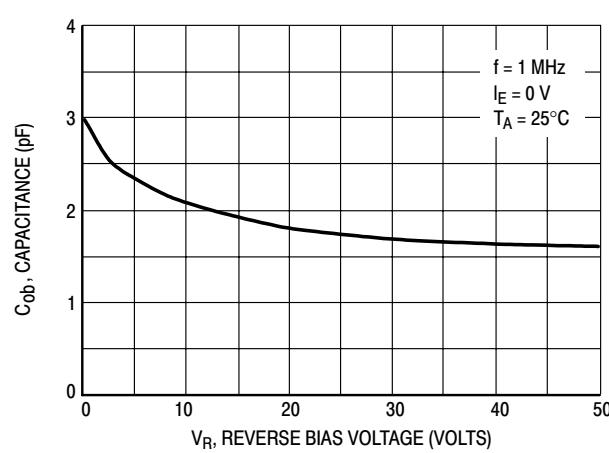
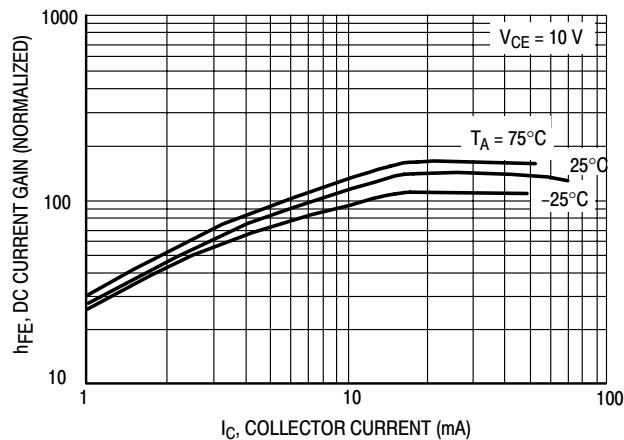
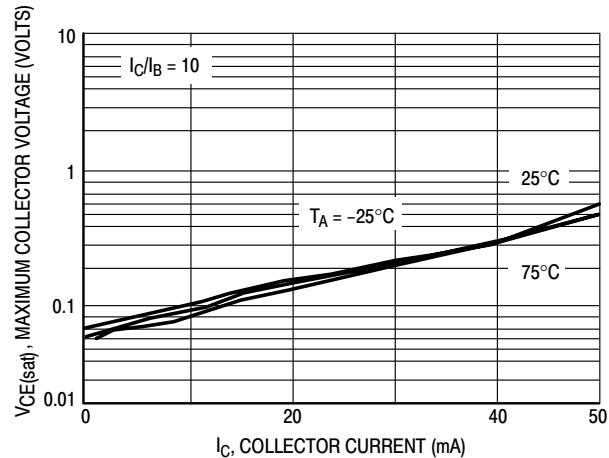
## LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series

### TYPICAL ELECTRICAL CHARACTERISTICS – LDTA114EM3T5G



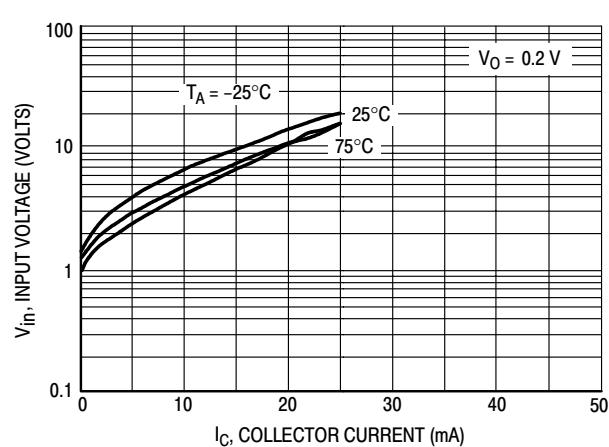
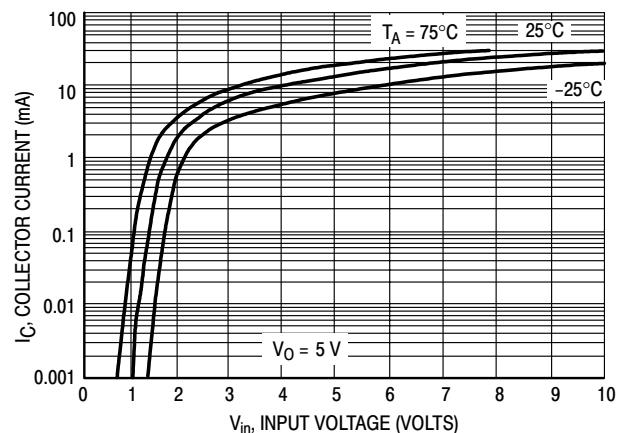
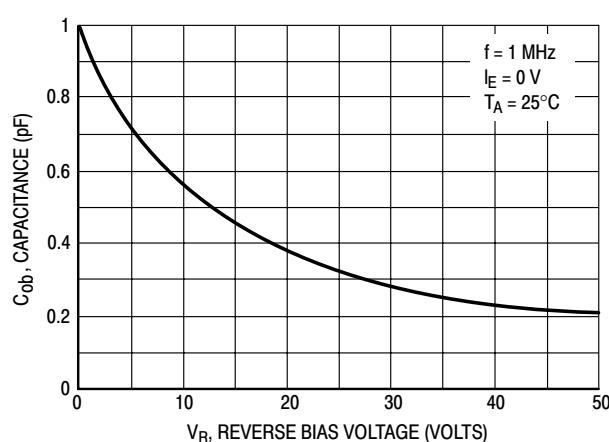
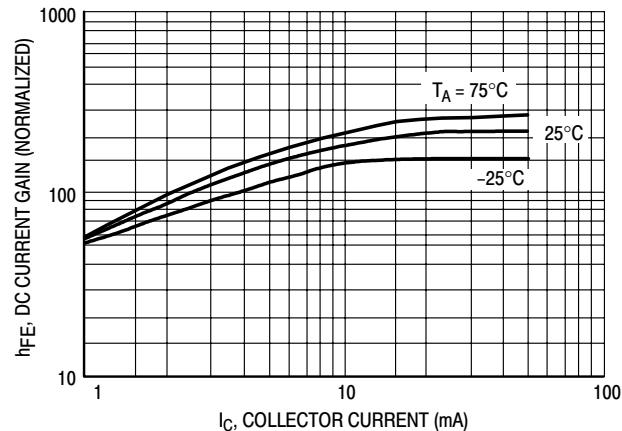
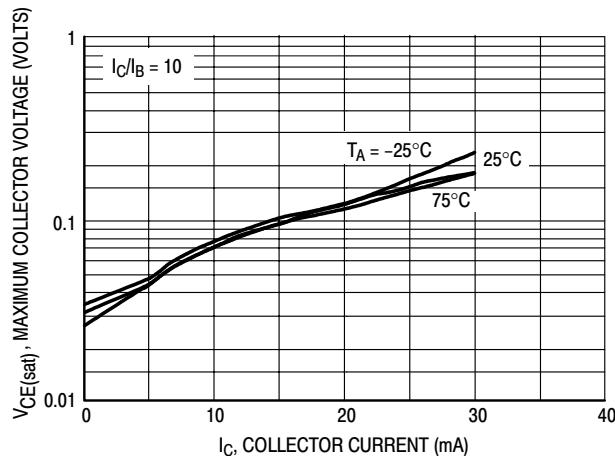
## LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series

### TYPICAL ELECTRICAL CHARACTERISTICS – LDTA124EM3T5G



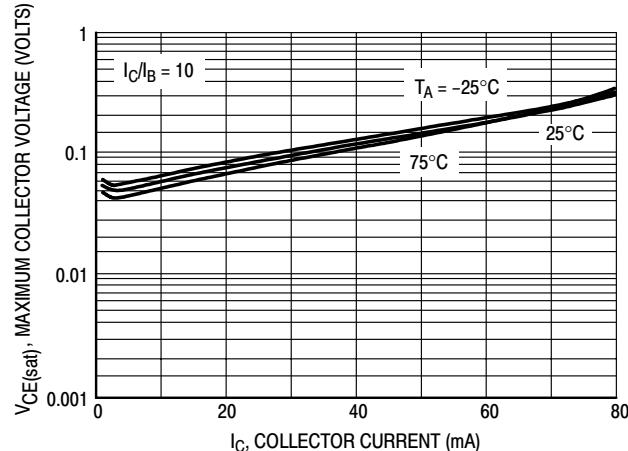
## LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series

### TYPICAL ELECTRICAL CHARACTERISTICS – LDTA144EM3T5G

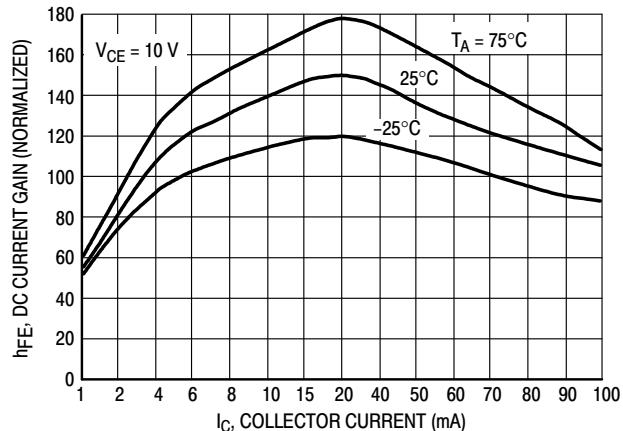


## LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series

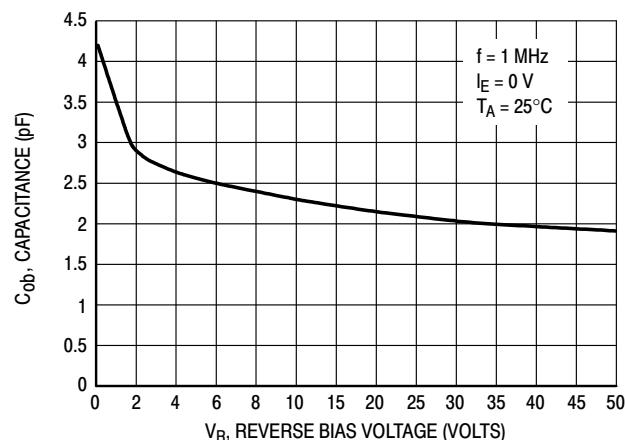
### TYPICAL ELECTRICAL CHARACTERISTICS – LDTA114YM3T5G



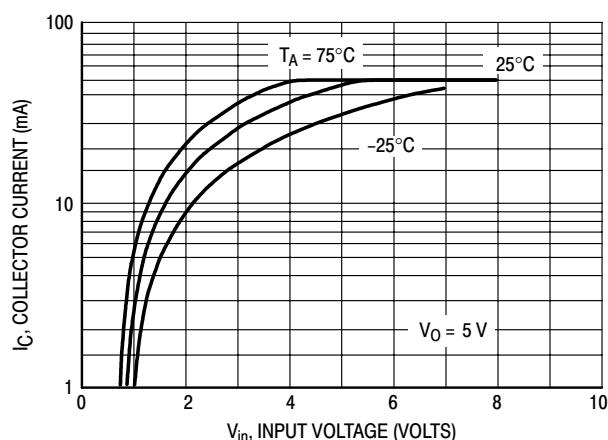
**Figure 17.  $V_{CE(\text{sat})}$  versus  $I_C$**



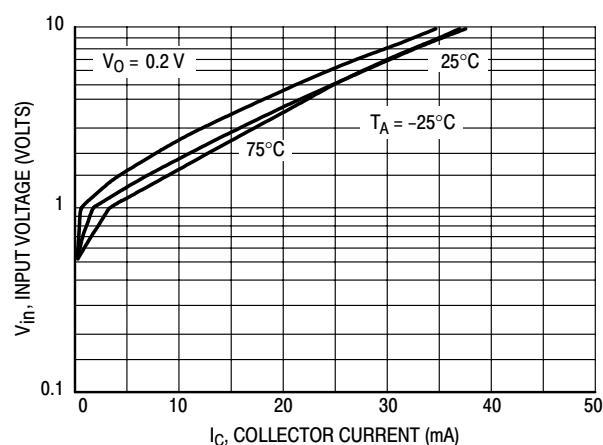
**Figure 18. DC Current Gain**



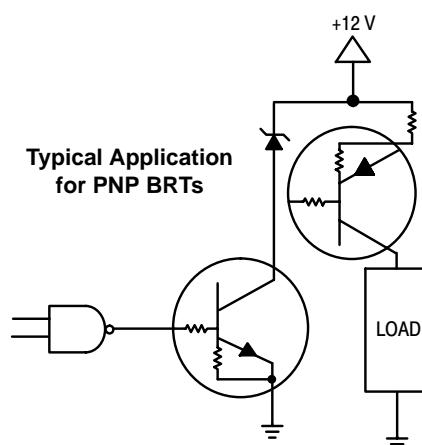
**Figure 19. Output Capacitance**



**Figure 20. Output Current versus Input Voltage**



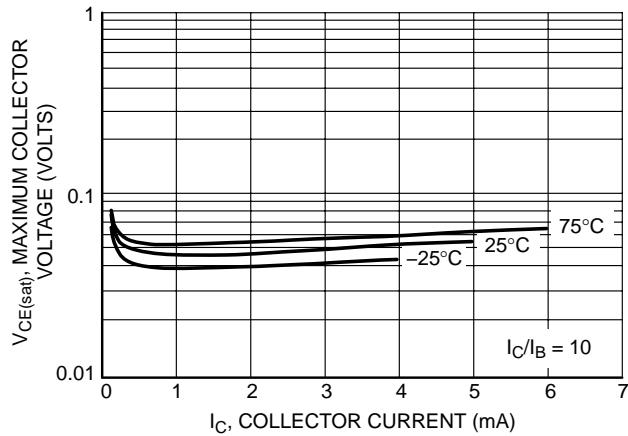
**Figure 21. Input Voltage versus Output Current**



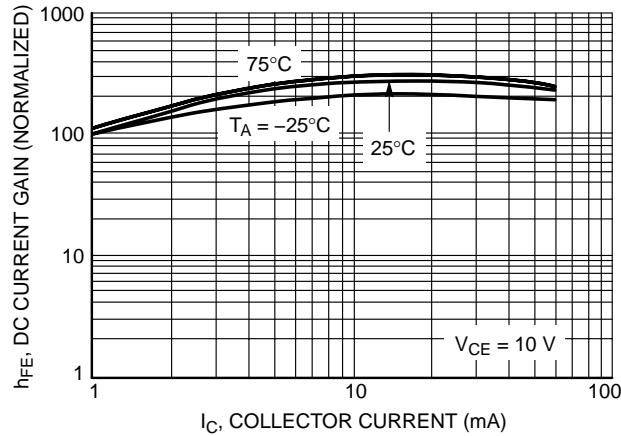
**Figure 22. Inexpensive, Unregulated Current Source**

## LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series

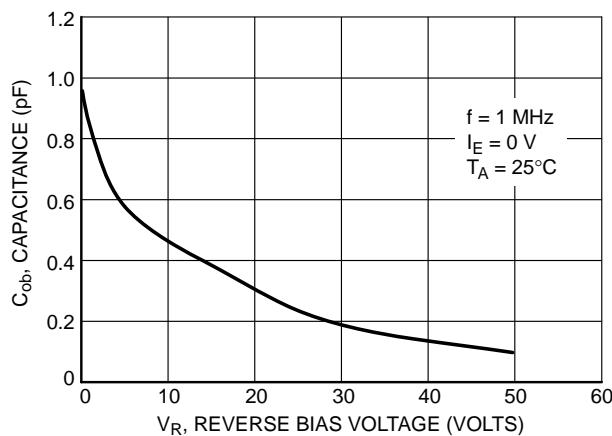
### TYPICAL ELECTRICAL CHARACTERISTICS — LDTA115EM3T5G



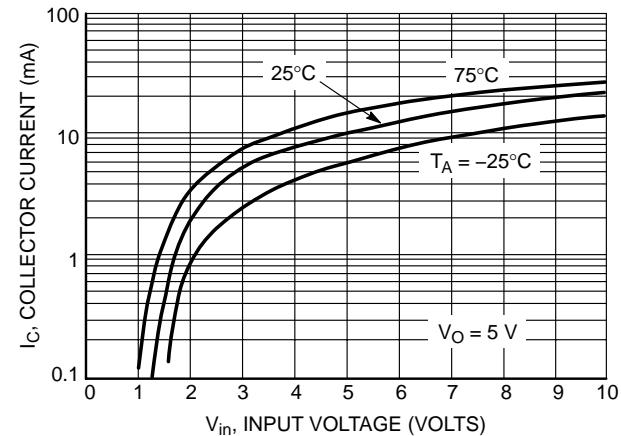
**Figure 23. Maximum Collector Voltage versus Collector Current**



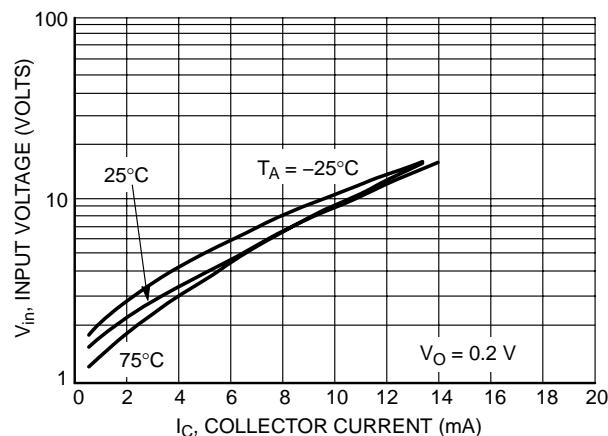
**Figure 24. DC Current Gain**



**Figure 25. Output Capacitance**



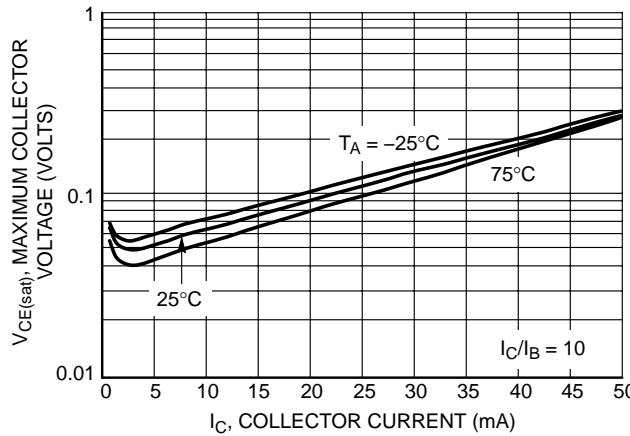
**Figure 26. Output Current versus Input Voltage**



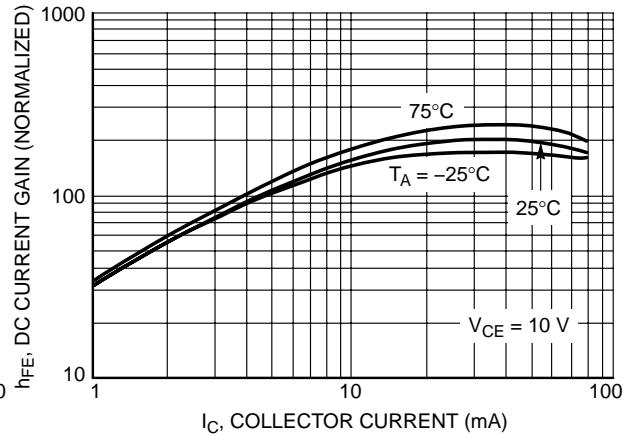
**Figure 27. Input Voltage versus Output Current**

## LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series

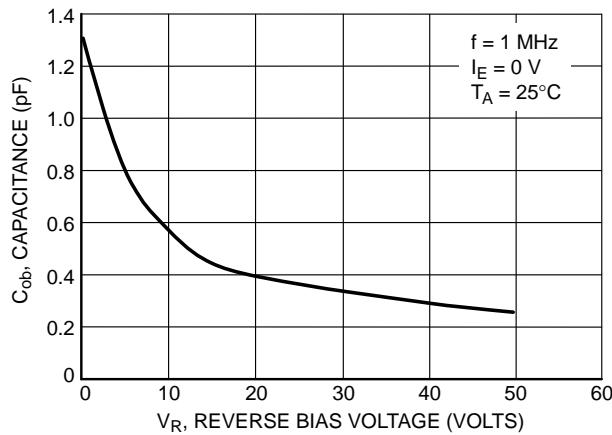
### TYPICAL ELECTRICAL CHARACTERISTICS — LDTA144WM3T5G



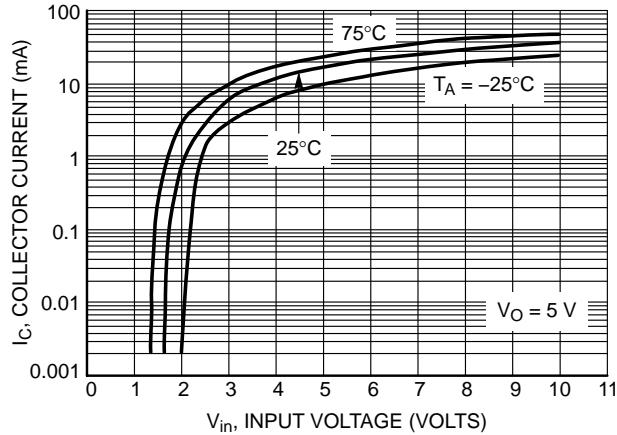
**Figure 28. Maximum Collector Voltage versus Collector Current**



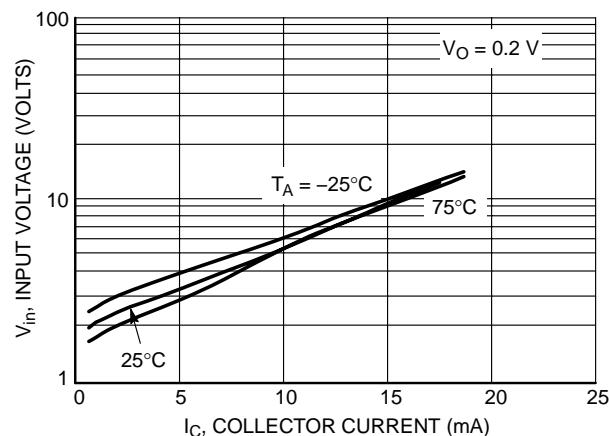
**Figure 29. DC Current Gain**



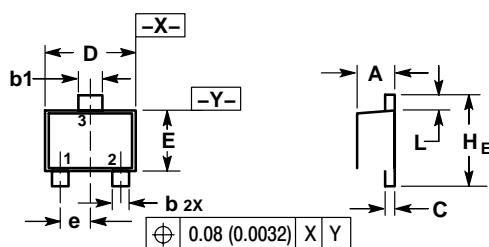
**Figure 30. Output Capacitance**



**Figure 31. Output Current versus Input Voltage**



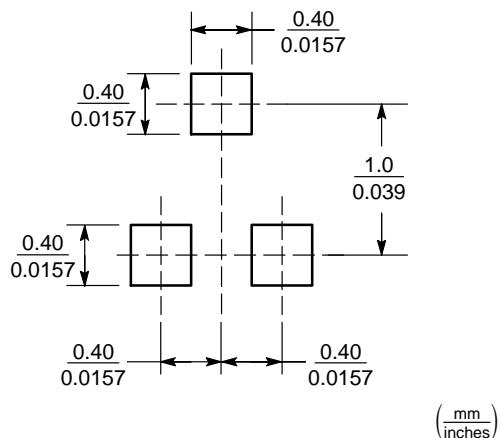
**Figure 32. Input Voltage versus Output Current**

**LDTA114EM3T5G Series ,S- LDTA114EM3T5G Series**
**PACKAGE DIMENSIONS**
**SOT-723**

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
b	0.15	0.20	0.27	0.0059	0.0079	0.0106
b1	0.25	0.3	0.35	0.010	0.012	0.014
C	0.07	0.12	0.17	0.0028	0.0047	0.0067
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.75	0.80	0.85	0.03	0.032	0.034
e	0.40 BSC			0.016 BSC		
H_E	1.15	1.20	1.25	0.045	0.047	0.049
L	0.15	0.20	0.25	0.0059	0.0079	0.0098

PIN 1. BASE  
2. Emitter  
3. Collector

**SOLDERING FOOTPRINT**


$(\frac{\text{mm}}{\text{inches}})$